

LB1688

3-Phase Brushless Motor Driver

Applications

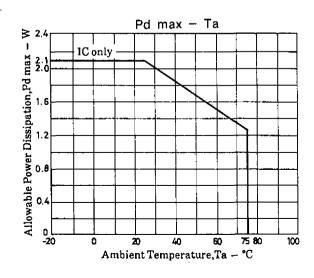
The LB1688 is a 3-phase brushless motor driver IC ideally suited for use in VTR capstan motor, drum motor drive applications.

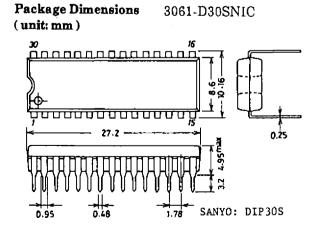
Features and Functions

- (1) 120° voltage linear type
- (2) Soft switching type eliminating noises caused by current switching and making the values of external capacitors smaller (comparable to those of chip capacitors)
- (3) On-chip thermal shutdown

Absolute Maximum Ratings at	$Ta = 25^{\circ}C$			unit	
Maximum Supply Voltage	$ m V_{CC}$ max1		20	V	
	$ m V_{CC}$ max2		7.0	V	
Output Supply Voltage	V _{OUT.V.W.}		22	V	
Output Current	I_{OUT}		1.5	Α	
Allowable Power Dissipation	Pd max		2.1	W	
Operating Temperature	Topr		-20 to +75	$^{\circ}\mathrm{C}$	
Storage Temperature	Tstg		-55 to +125	$^{\circ}\mathrm{C}$	
Allowable Operating Condition		unit			
Supply Voltage	$V_{CC}1$		8.5 to 18	V	
	$V_{\rm CC}2$		4.3 to 6.5	V	
Electrical Characteristics at Ta [Power Supply]	$a = 25$ °C, V_{CC} 1	$1 = 12V, V_{CC}2 = 5V$	min typ	max	unit
Supply Current 1	$I_{CC}1$	$V_C = 0, R_L = \infty$	17	30	mA
Supply Current 2	$I_{CC}2$	$V_C = 0$	6.5	9.5	mA

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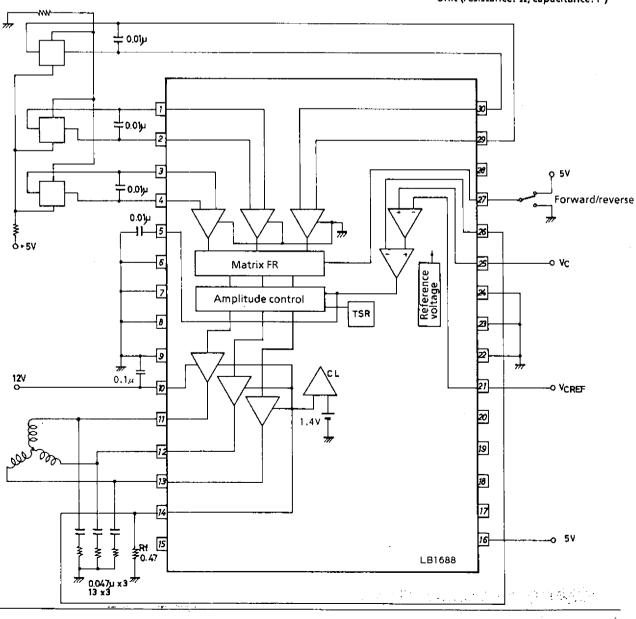


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[Output]			min	typ	max	unit
Output Saturation Voltage	$V_{O(sat)}1$	$I_{OUT} = 0.5A$, sink + source		1.6	2.2	V
-	$V_{O(sat)}2$	$I_{OUT} = 1.0A$, sink + source		2.0	3.0	V
Output TRS Voltage .	$V_{O(sus)}$	I _{OUT} =20mA (See note.)	20			V
Output Quiescent Voltage	V_{QQ}	$V_C = 0$	5.8	6.1	6.4	V
[Hall Input-Output]	·					
Hall Amp Input Offset Voltage	V_{H} offset		-5		+5	mV
Hall Amp Input Bias Current	I _H bias			1	5	μA
Hall Amp Common-Mode	$ m V_{H}ch$		1.3		3.7	V
Input Voltage Range						
Hall Input-Output Voltage Gain	$G_{ m VHO}$			43		dB
[Control-Output]						
Control-Output Drive Gain	$G_{ m VCO}$		38	41	44	dΒ
Control-Output CH Difference	ΔG_{VCO}		-2		+2	dB
[Motor Detection]						
Thermal Shutdown Temperature	$\mathrm{T_{SD}}$	(See note.)	150	180	210	°C
Thermal Shutdown Hysteresis	ΔT_{SD}	(See note.)		15		$^{\circ}\mathrm{C}$

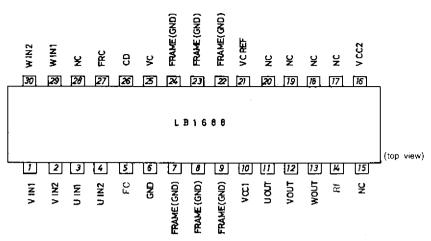
 $Note: Values shown are design targets only. \ No \ measurements \ have been \ taken.$

Equivalent Circuit Block Diagram

Unit (resistance: Ω, capacitance: F)



Pin Assignment



Note: All FRAME pins are connected to GND.

Pin Description

Pin Name	Pin No.	Description			
$U_{\rm IN}$ 1, $U_{\rm IN}$ 2	3, 4	U phase hall element input pin. 'H' of logic: V _{IN} 1 > V _{IN} 2			
$V_{IN}1, V_{IN}2$	1,2	V phase hall element input pin. 'H' of logic: $V_{IN}1 > V_{IN}2$			
$W_{IN}1, W_{IN}2$	29, 30	W phase hall element input pin. 'H' of logic : $V_{IN}1>V_{IN}2$			
U_{OUT}	11	U phase output pin			
$v_{ m OUT}$	12	V phase output pin			
W_{OUT}	13	W phase output pin			
V _{CC} 1	10	Power supply pin for applying output			
V _{CC} 2	16	Power supply pin for applying voltage to each section other than output section. This voltage must be stabilized to be free from ripple, noise, etc.			
Rf	14	Output current detect pin. By connecting Rf across this pin and GND pin, output current is detected as voltage. The result is used to control the overcurrent protection circuit.			
CD	26	Pin for fetching current (voltage) detected with Rf. Takes feedback from Rf to reduce output voltage gain. Ground when not in use.			
FC	5	Frequency characteristic correction			
v_c	25	Speed-phase control pin			
		Control is of voltage-controlled type that controls output voltage.			
V _{CREF}	21	Control reference voltage			
GND	6	GND for other than output			
		Minimum potential of output transistor is at Rf pin.			
F/RC	27	Forward/reverse control pin			
		By setting this pin to 'H' (more than 2.0V)/'L' (less than 0.3V), truth			
		value is changed to perform forward/reverse rotation.			

Truth Table

	Source			Input		Forward/Reverse Control		
			Şink	U	V	w	F/RC	
	W phase	e → V phase	V phase	н н	,	L		
1	V phase	→	W phase			L	Н	
2	W phase	- →	U phase		L	L	L	
2	U phase	→	W phase	Н			Н	
3	V phase	→	W phase	L	L L	Н	L	
J	W phase	→	V phase				Н	
4	U phase	→	V phase	,		,	L	
4	V phase	→	U phase	LH		L	Н	
5	V phase	→	U phase		H L		7,7	L
ō	U phase	→	V phase	п	L	Н	Н	
_	U phase	→	W phase		••	<u> </u>	L	
6	W phase	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	н	Н				

Input:

- H: High level. One of the inputs should have a potential at least 0.2V higher than the other.
- L: Low level. One of the inputs should have a potential at least 0.2V lower than the other.

Forward/reverse control:

H: 2.0 to V_{CC}2

L: 0 to 0.3V

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